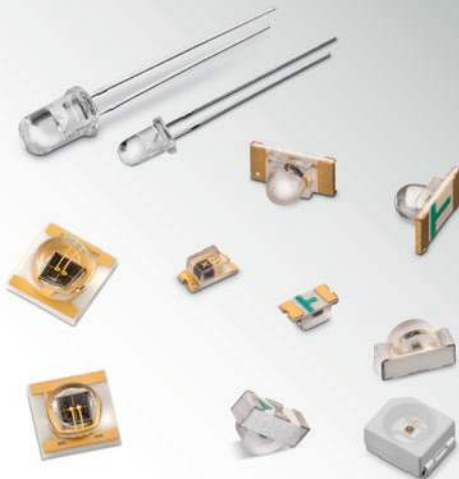




DESIGN KIT

Infrared LEDs



SIZE:

3 mm / 5 mm / 0603 / 1206 / 1104 / 3528 / 3535

TECHNICAL DATA:

THT Infrared
Infrared Chip LED
Infrared Top LED
Infrared Ceramic

Order Code 154 150
Version 1.0

DESIGN KIT

Infrared LEDs



3 mm	0603	1104	3528	3535
154 003 85A 3590	154 060 85B A300	154 114 85A A370	154 141 85B A210	154 353 85A 9050
λ_{peak} @ 50 mA: 850 nm	λ_{peak} @ 20 mA: 850 nm	λ_{peak} @ 20 mA: 850 nm	λ_{peak} @ 50 mA: 850 nm	λ_{peak} @ 1000 mA: 850 nm
I_e typ. @ 50 mA: 60 mW/sr	I_e typ. @ 20 mA: 2 mW/sr	I_e typ. @ 20 mA: 2 mW/sr	I_e typ. @ 50 mA: 9 mW/sr	I_e typ. @ 1000 mA: 350 mW/sr
V_f typ. @ 50 mA: 1.5 V	V_f typ. @ 20 mA: 1.4 V	V_f typ. @ 20 mA: 1.4 V	V_f typ. @ 50 mA: 1.5 V	V_f typ. @ 1000 mA: 2.2 V
$2\theta_{50\%}$ typ. @ 50 mA: 35 °	$2\theta_{50\%}$ typ. @ 20 mA: 130 °	$2\theta_{50\%}$ typ. @ 20 mA: 130 °	$2\theta_{50\%}$ typ. @ 50 mA: 120 °	$2\theta_{50\%}$ typ. @ 1000 mA: 90 °
154 003 94A 3590	154 060 94B A500	154 114 94A A570	154 141 94B A210	154 353 94A 9050
λ_{peak} @ 50 mA: 940 nm	λ_{peak} @ 20 mA: 940 nm	λ_{peak} @ 20 mA: 940 nm	λ_{peak} @ 50 mA: 940 nm	λ_{peak} @ 1000 mA: 940 nm
I_e typ. @ 50 mA: 30 mW/sr	I_e typ. @ 20 mA: 0.8 mW/sr	I_e typ. @ 20 mA: 1 mW/sr	I_e typ. @ 50 mA: 8 mW/sr	I_e typ. @ 1000 mA: 300 mW/sr
V_f typ. @ 50 mA: 1.3 V	V_f typ. @ 20 mA: 1.2 V	V_f typ. @ 20 mA: 1.2 V	V_f typ. @ 50 mA: 1.4 V	V_f typ. @ 1000 mA: 1.9 V
$2\theta_{50\%}$ typ. @ 50 mA: 35 °	$2\theta_{50\%}$ typ. @ 20 mA: 150 °	$2\theta_{50\%}$ typ. @ 20 mA: 150 °	$2\theta_{50\%}$ typ. @ 50 mA: 120 °	$2\theta_{50\%}$ typ. @ 1000 mA: 90 °
5 mm	1206 dome			
154 005 85A 3590	154 120 85A 3060			154 353 85A A350
λ_{peak} @ 50 mA: 850 nm	λ_{peak} @ 20 mA: 850 nm			λ_{peak} @ 1000 mA: 850 nm
I_e typ. @ 50 mA: 85 mW/sr	I_e typ. @ 20 mA: 20 mW/sr			I_e typ. @ 1000 mA: 250 mW/sr
V_f typ. @ 50 mA: 1.5 V	V_f typ. @ 20 mA: 1.4 V			V_f typ. @ 1000 mA: 2.2 V
$2\theta_{50\%}$ typ. @ 50 mA: 35 °	$2\theta_{50\%}$ typ. @ 20 mA: 30 °			$2\theta_{50\%}$ typ. @ 1000 mA: 130 °
154 005 94A 3590	154 120 94A 3060			154 353 94A A350
λ_{peak} @ 50 mA: 940 nm	λ_{peak} @ 20 mA: 940 nm			λ_{peak} @ 1000 mA: 940 nm
I_e typ. @ 50 mA: 30 mW/sr	I_e typ. @ 20 mA: 5 mW/sr			I_e typ. @ 1000 mA: 220 mW/sr
V_f typ. @ 50 mA: 1.3 V	V_f typ. @ 20 mA: 1.2 V			V_f typ. @ 1000 mA: 1.9 V
$2\theta_{50\%}$ typ. @ 50 mA: 35 °	$2\theta_{50\%}$ typ. @ 20 mA: 30 °			$2\theta_{50\%}$ typ. @ 1000 mA: 130 °

Important information: Würth Elektronik's design kits contain reference components. These components correspond with the current product development status on the day of supply. Exchange of the reference components to components with up-to-date product development status is not carried out automatically. No liability is taken for the use of these reference components. Therefore, please request new samples prior to releases for series production and product release.

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